

**Product data sheet** 

### 1. General description

Planar passivated very sensitive gate four quadrant triac in a TO-92 plastic package intended for interfacing with low power drivers including microcontrollers.

### 2. Features and benefits

- · High blocking voltage capability
- Very sensitive gate
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drive circuits and microcontrollers

### 3. Applications

- General purpose motor control
- General purpose switching
- · Air conditioner indoor fan control

### 4. Quick reference data

Symbol	Parameter	Conditions	Va	Values		Unit
Absolute	maximum rating	·				
V <sub>DRM</sub>	repetitive peak off-state voltage			600		V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 51 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		1		A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		12.5		A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$		13.7		A
Tj	junction temperature			125		°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics	·			_	
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	0.4	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	1.3	3	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	1.4	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	3.8	7	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	1.3	5	mA
V <sub>T</sub>	on-state voltage	I <sub>τ</sub> = 1.4 A; T <sub>i</sub> = 25 °C; <u>Fig. 10</u>		1.2	1	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage		10	20	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_{D}$ = 400 V; T <sub>j</sub> = 125 °C; dI <sub>com</sub> /dt = 0.5 A/ms; I <sub>T</sub> = 1 A; gate open circuit	2	-	-	V/µs

# 5. Pinning information

Table 2. P	inning infor	nation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2	<b></b>	
2	G	gate		N
3	T1	main terminal 1	ТПП ЦЦЦ ЦЦЦ ТО-92 (SOT54)	T2 T1 G sym051

# 6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BT131-600	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54		

# 7. Marking

Table 4. Marking codes	
Type number	Marking codes
BT131-600	131-6

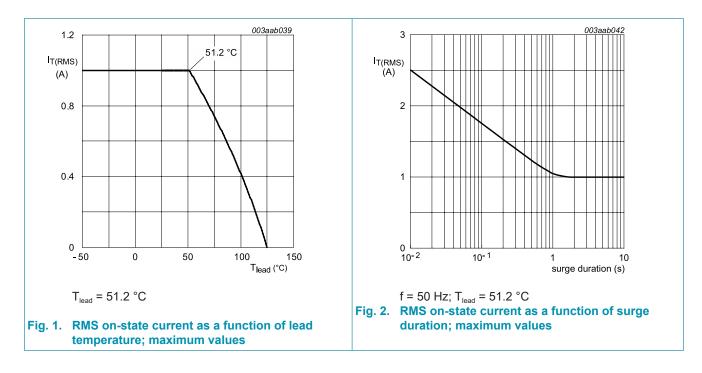
# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage [1]		600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{lead} \le 51 \text{ °C}$ ; Fig 1; Fig 2; Fig 3	1	А
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; Fig.4; Fig.5$	12.5	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$	13.7	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$t_P$ = 10 ms; sine-wave pulse	0.78	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state	I <sub>G</sub> = 6 mA; T2+ G+	50	A/µs
	current	I <sub>G</sub> = 6 mA; T2+ G-	50	A/µs
		I <sub>G</sub> = 6 mA; T2- G-	50	A/µs
		I <sub>G</sub> = 14 mA; T2- G+	10	A/µs
I <sub>GM</sub>	peak gate current		2	А
P <sub>GM</sub>	peak gate power		5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	0.1	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>j</sub>	junction temperature		125	°C

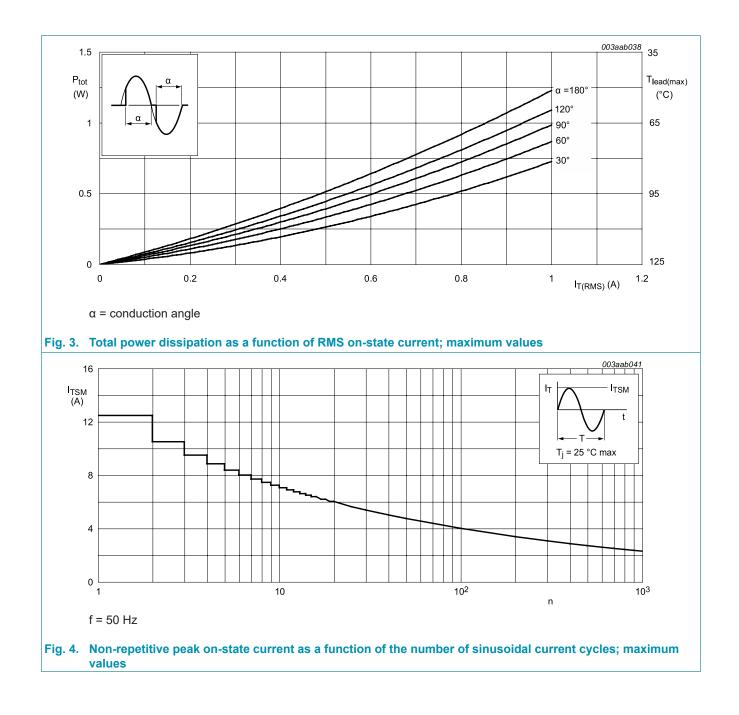
[1] Although not recommended, off-state voltage up to  $V_{DRM}$  may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed  $3A/\mu s$ .



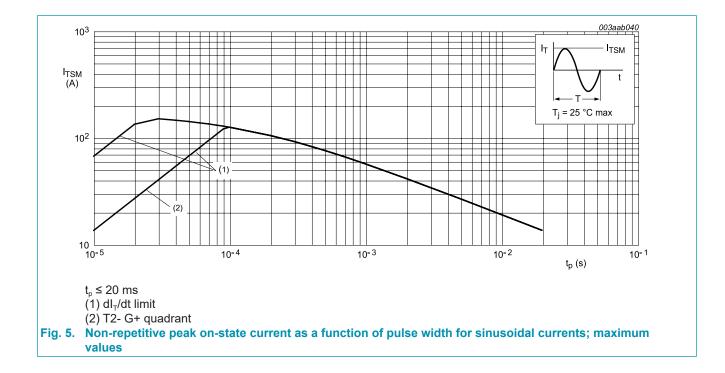
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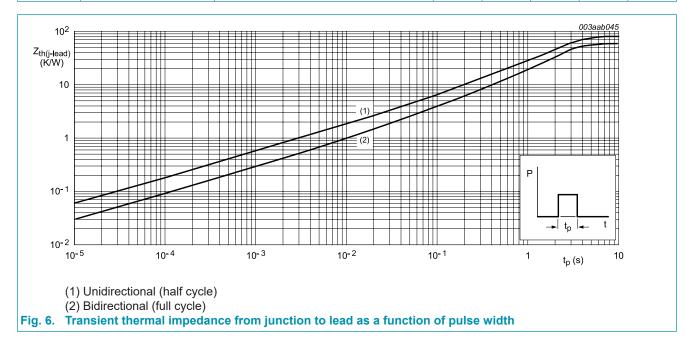






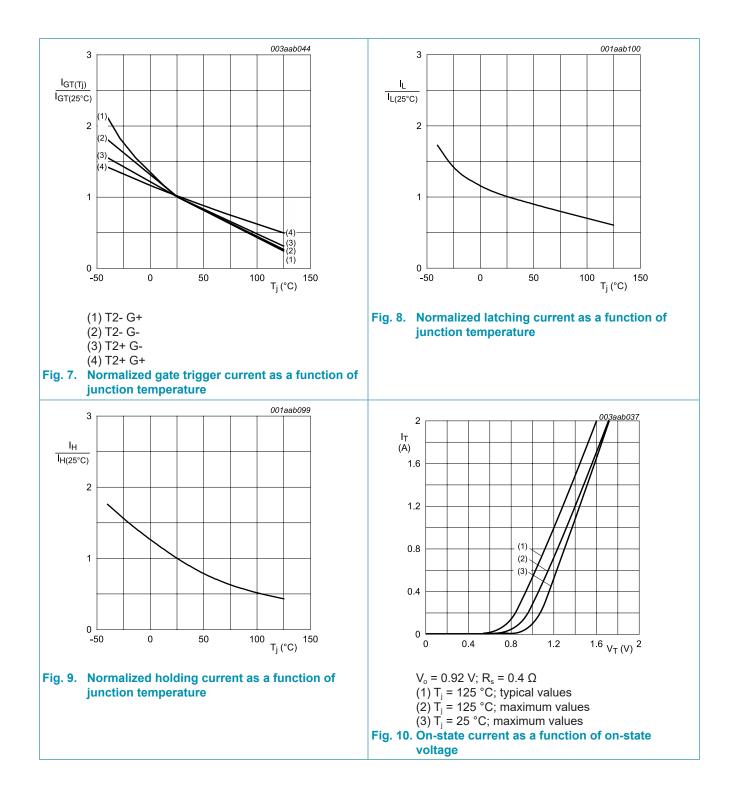
## 9. Thermal characteristics

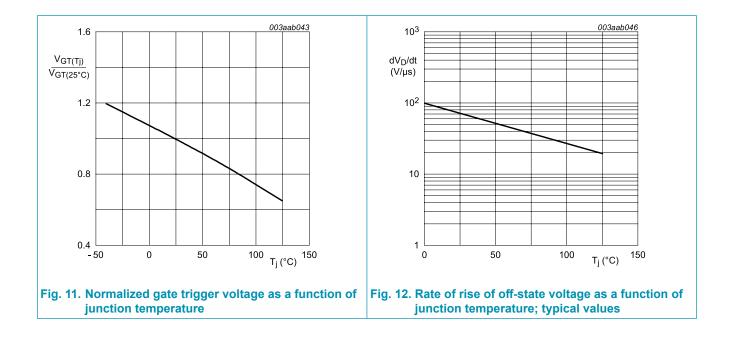
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance	full cycle; <u>Fig 6</u>	-	-	60	K/W
	from junction to lead	half cycle; <u>Fig 6</u>	-	-	80	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



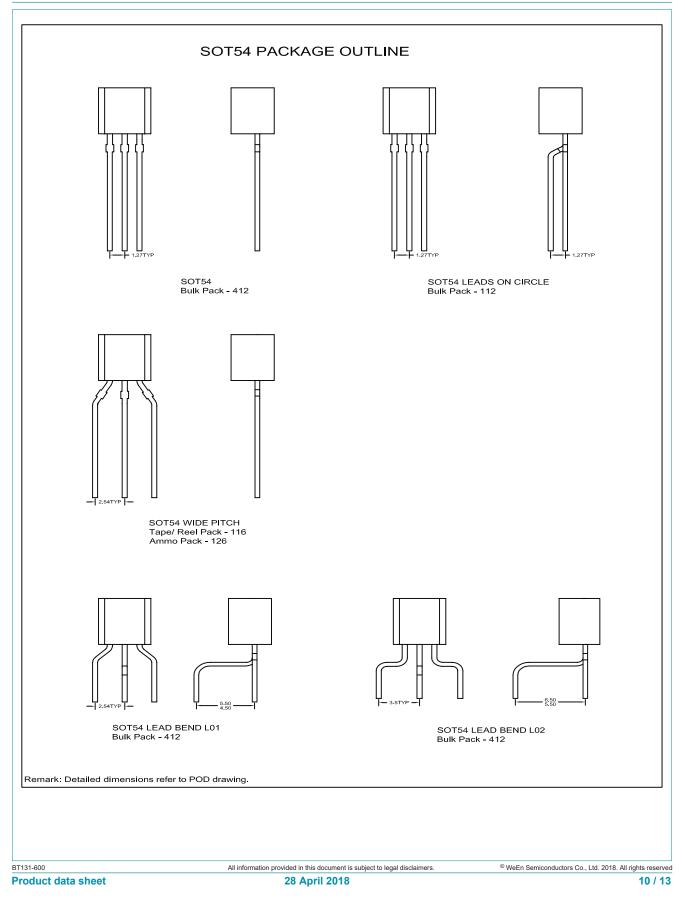
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	· · · · ·				
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \overline{\text{Fig. 7}}$	-	0.4	3	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	1.3	3	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	1.4	3	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	3.8	7	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; Fig. 8	-	1.2	5	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	4	8	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	1	5	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	2.5	8	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	1.3	5	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.4 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.7	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; <u>Fig. 11</u>	0.2	0.3	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage		10	20	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ dI}_{com}/\text{dt} = 0.5 \text{ A}/\text{ms}; \text{ I}_T = 1 \text{ A}; \text{ gate open circuit}$	2	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{\rm TM}$ = 1.5 A; $V_{\rm D}$ = 600 V; $I_{\rm G}$ = 0.1 A; $dI_{\rm G}/$ $dt$ = 5 A/ $\mu s$	-	2	-	μs





# 11. Package outline



#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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